



A DISRUPTIVE TECHNOLOGY FOR STORAGE CLASS MEMORY

Investor Open Briefing – Feb 2018

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Welcome - Jim Dorrian



- + Jim Dorrian is the non-executive Chairman of 4DS.
Former partner at Crosspoint Venture Partners, a prestigious Silicon Valley VC firm.
Been a CEO and Board Member of several multinational Silicon Valley companies.
Holds a Bachelor of Arts in Economics and Communications from Indiana University.
- + Invested over A\$1 mil cash in 4DS since taking Chair, more recently an additional A\$250,000 in early 2018
- + Substantial shareholder – over 50 million shares
- + Has never taken any salary or fees – following ASX listing, directors fees are taken in scrip each year at June 30 price
- + Has founded and exited Silicon Valley companies with cumulative exit value in excess of US\$7 billion



US\$1 billion



US\$4 billion



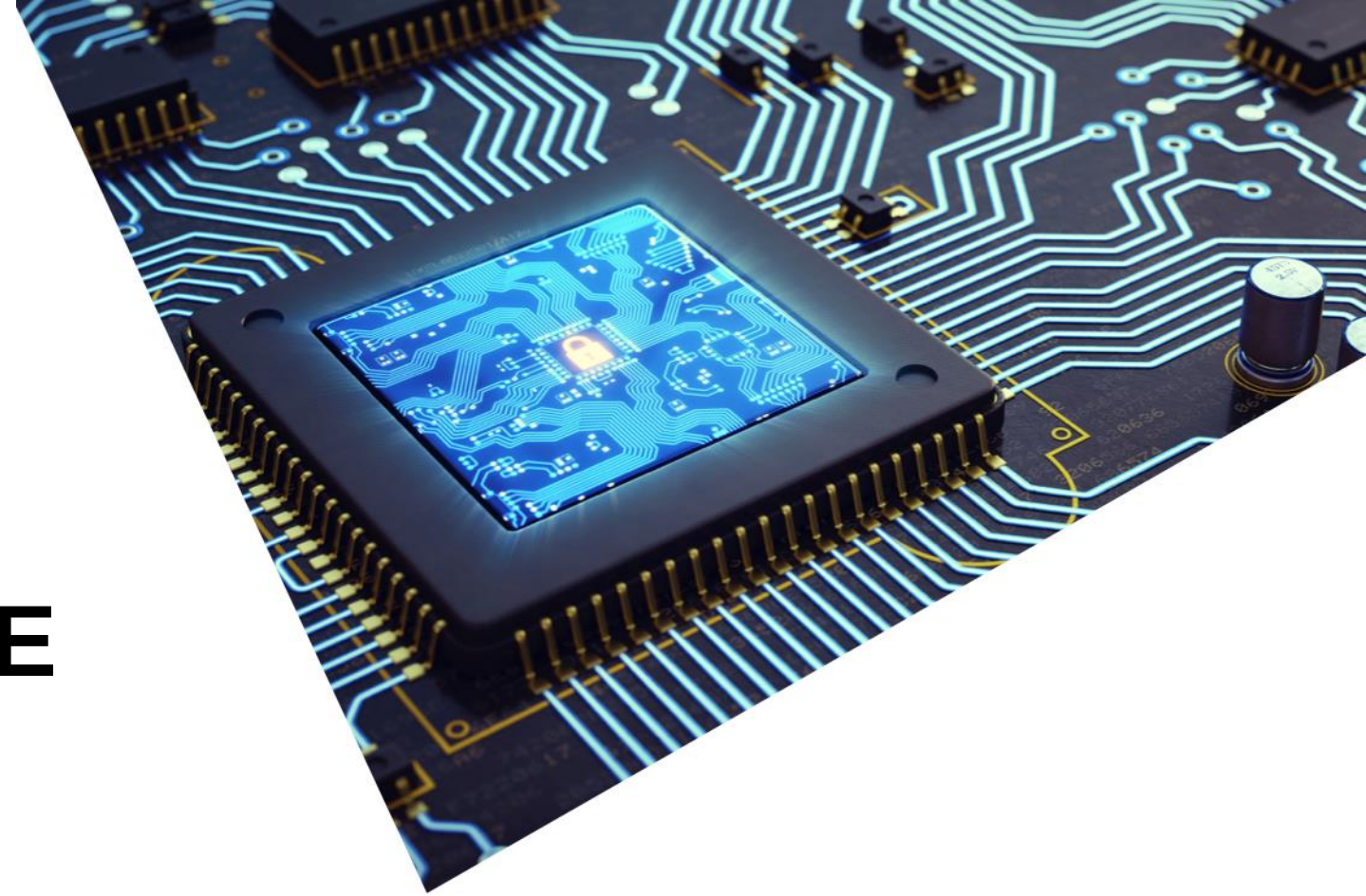
US\$610 million



US\$440 million

GLOBAL DATA EXPLOSION PRESENTS HUGE CHALLENGES.

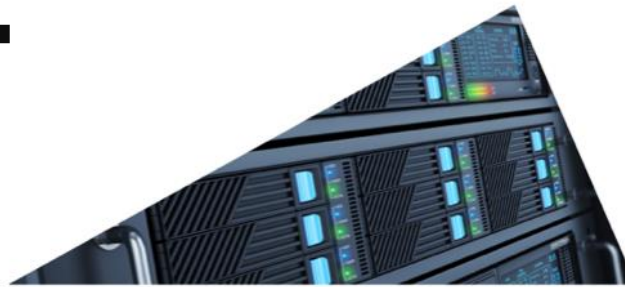
The semiconductor industry recognises the challenge and is investing billions of dollars annually on research and development to create a solution.



THE CHALLENGE. +

DRAM and NAND Flash are the main technologies utilized today.

Both are US\$40-50 billion annual markets – and growing.

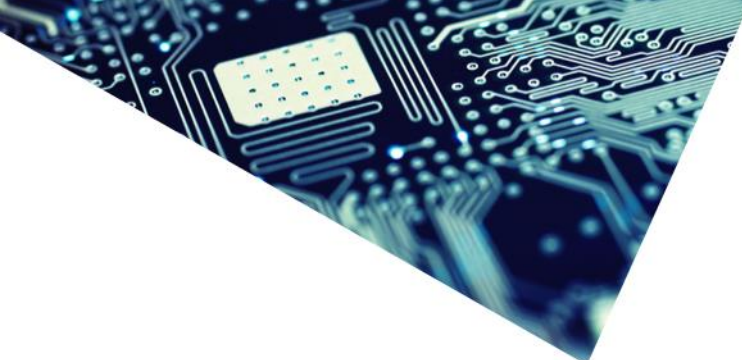


+ DRAM is super-fast, has exceptional endurance but is expensive and volatile



+ NAND Flash is slow, has limited endurance but is cheap and non-volatile

A new innovation is required and the industry refers to it as **Storage Class Memory** - over time this is predicted to have a market size as large as DRAM and NAND Flash

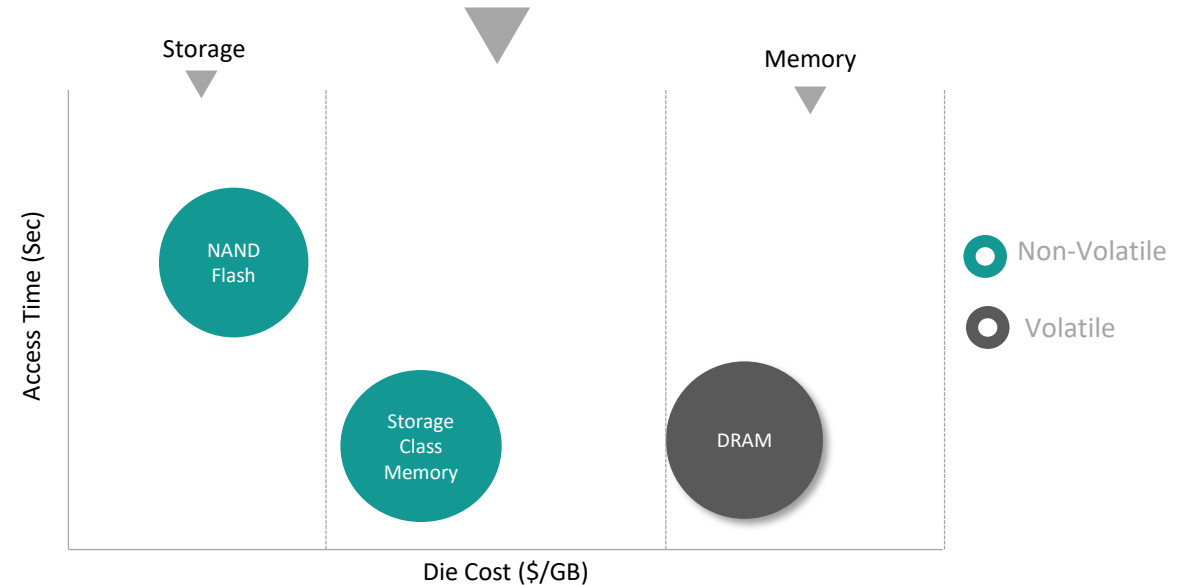


STORAGE CLASS MEMORY. +

Emerging as the leading new category to extend the memory hierarchy.

STORAGE CLASS MEMORY

Combines the best characteristics of DRAM and NAND Flash



Battleground for next generation memory technology.

- + **Faster** – DRAM-like read speed
- + **Cheaper** – NAND Flash-like costs
- + **Non-volatile** – Retains data when power is off

THE STORAGE CLASS MEMORY SOLUTION. +



- + **World-leading** Silicon Valley based Interface Switching ReRAM developer
- + 4DS is the most **advanced Interface Switching ReRAM**
- + **19 US patents** developed and granted and 4 pending
- + **The most promising Interface Switching ReRAM cell for Storage Class Memory**
- + **Joint development agreement** with Western Digital subsidiary HGST since 2014
- + **Strategic collaboration with imec** signed in November 2017
- + Successful placement/option exercise in November 2017 raised **A\$3.83 mil**

STORAGE CLASS MEMORY REQUIREMENTS.⁺

Requirements

- Based on well-understood physics to be sustainable over generations
- Area based to achieve cost and density as close as possible to NAND Flash
- Capable of speed comparable to DRAM
- Endurance suitable for Storage Class Memory
- As much retention as possible to meet Storage Class Memory requirements
- As much retention as possible without sacrificing speed and endurance
- Tunable technology in the vast opportunity between DRAM and NAND Flash



STORAGE CLASS MEMORY REQUIREMENTS.⁺

4DS

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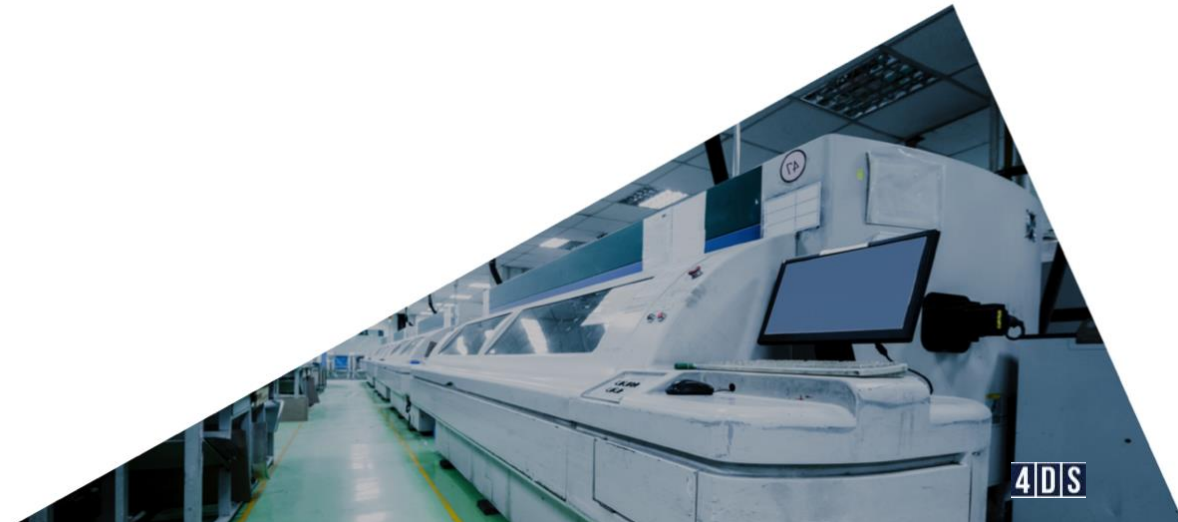
- Tunable technology in the vast opportunity between DRAM and NAND Flash



PARAMETERS NEEDED MET.

4DS Interface Switching ReRAM has displayed enough relevant and meaningful data in each category to now move immediately to production of a Megabit chip, a giant step forward.

-  Scales to geometries needed for high-density memory and 3D : 40nm memory cell
-  Endurance far exceeds NAND Flash
-  Endurance yield >97%
-  Read speed comparable to DRAM – **an area-based ReRAM first**
-  No need for speed crippling error correction – **a ReRAM first**
-  Retention data adequate for Storage Class Memory



imec + COLLABORATION AGREEMENT.

imec, is the **world's #1** independent semiconductor development institute

- + Collaborates with the who's who of electronic products and systems
- + Collaborates with makers of high-volume high-density memories
- + Has a world leading track record in the transfer of semiconductor processes
- + Uses the same tools as industry for high-volume production of high-density memories
- + Has a proven megabit memory platform to fast track development of Megabit chip
- + Used this platform to explore a wide range of emerging memories



imec + COLLABORATION OBJECTIVES.

- + Imec and 4DS have **already commenced** the 2018 development schedule
- + End goal is to fabricate a megabit **4DS Interface Switching chip with a fully functioning memory**
- + Develop a **fully transferable** fabrication compatible process
- + **Mimic industry standard** high volume production
- + Utilizing imec's proven megabit memory platform **reduces time and cost**
- + Report technical progress to shareholders – more often upon significant developments



JOINT DEVELOPMENT AGREEMENT. +

HGST, is a subsidiary of Western Digital Corporation (US\$27 billion market cap), the largest global leader in digital storage.

- + Strategic innovator in emerging high growth technologies
- + Commenced JDA in 2014 – **Renewed in 2015, 2016 and 2017**
- + Insight into what is important in a data-centric world
- + Siva Sivaram, Head of Memory at Western Digital, commented **“We are committed to ReRAM, it is scalable with greater density, lower cost and latency and longer endurance”***



SUMMARY. +

- + 4DS is developing a **breakthrough Interface Switching ReRAM Storage Class Memory** solution
- + **Significant progress to date is pivotal for Storage Class Memory**
- + Four year strategic partnership with HGST, **leader in digital storage**
- + **Imec** - strategic collaboration to develop megabit chip with the **world-leading researcher in nano electronics**
- + Consistently achieves stated milestones
- + **Strong patent portfolio with 19 granted patents** wholly owned and developed in-house
- + **World-class team** of memory specialists, material scientists and test engineers
- + Board experienced in founding, building and **exiting high tech companies**
- + **Sufficient cash to meet current objectives**

4DS is addressing the massive memory demands of tomorrow



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THANK YOU

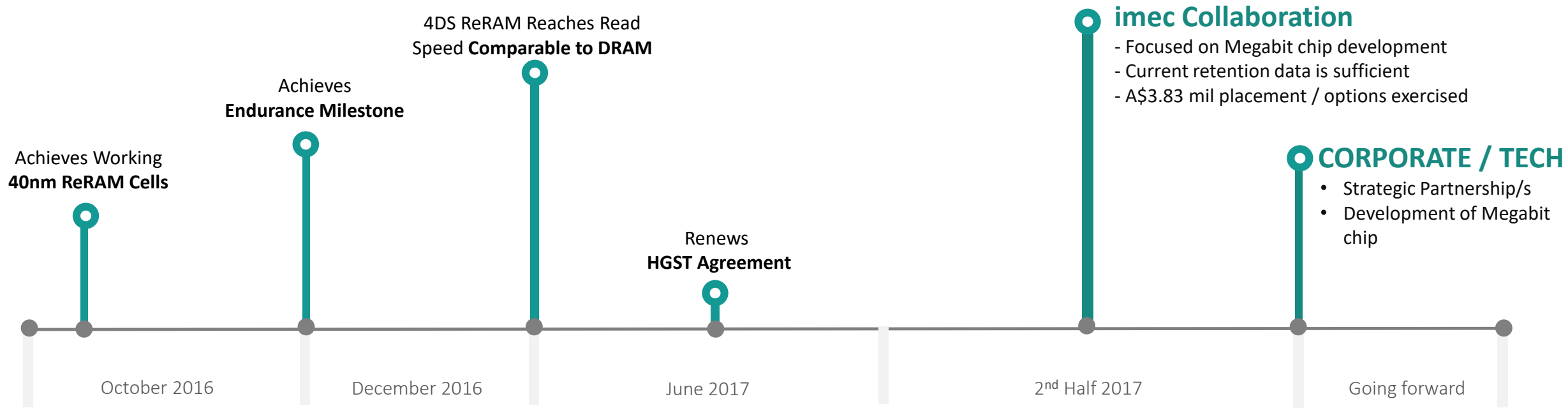
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Fremont CA 94539
UNITED STATES

AUSTRALIA

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West Perth WA 6005
AUSTRALIA

THE LEAP TO STORAGE CLASS MEMORY. +



BOARD AND MANAGEMENT. +

Global expertise founding and building high-tech companies.



**JIM
DORRIAN**

Non-Executive Chairman

- Served as CEO of several Silicon Valley companies
- Extensive M&A experience
- Partner at VC firm Crosspoint Venture Partners

Last transaction was the sale of Bill Me Later – a company Jim founded and sold to PayPal for US\$1 billion



**Dr GUIDO
ARNOUT**

CEO & Managing Director

- 30+ years in commercialising electronics technology
- Successes include, Power-Escape, CoWare, CrossCheck Technology and Silvar-Liso



**HOWARD
DIGBY**

Non-Executive Director

- Former senior roles at IBM, Adobe, Gartner and the Economist Group
- Non-Executive Director Elsie Ltd and Chairman of Omni Market Ltd
- Advisor to a number of early stage technology companies



**Dr SESHUBABU
DESU**

Chief Technology Officer

- Expert in thin films, semiconductor processing and non-volatile memories
- Professor, Dean and Head of Electrical Engineering at various universities



**DAVID
McAULIFFE**

Executive Director

- Experienced company director
- Involved in numerous capital raisings and in-licensing of technologies
- Founder of several companies in Australia, France and the UK, many of which are now ASX listed



**MICHAEL
VAN BUSKIRK**

Chief Engineering Officer

- Executive roles with a number of leading memory companies in Silicon Valley
- These include, Adesto Technologies Corporation, Innovative Silicon Inc and Spansion Inc.

CAPITAL + STRUCTURE.

ASX Code	4DS
Market Cap (Fully Diluted)	A\$86 Million*
Ordinary Shares on Issue	942 Million
Unlisted Options	124 Million
Cash	~A\$4.5 Million – Feb 2018
Board and Management	15%
Top 20	33%

* As at 2nd Feb 2018